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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	8051
Core Size	8-Bit
Speed	16MHz
Connectivity	EBI/EMI, UART/USART
Peripherals	POR
Number of I/O	32
Program Memory Size	8KB (8K x 8)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	44-QFP
Supplier Device Package	44-PQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/p87c52sbbb-557

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

80C51/87C51 ORDERING INFORMATION

	MEMORY SIZE 4K × 8	TEMPERATURE RANGE °C AND PACKAGE	VOLTAGE RANGE	FREQ. (MHz)	DWG. #
ROM	P80C51SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C51SBPN				
ROM	P80C51SBAA	0 to +70, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C51SBAA				
ROM	P80C51SBBB	0 to +70, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C51SBBB				
ROM	P80C51SFPN	–40 to +85, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C51SFPN				
ROM	P80C51SFA A	–40 to +85, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C51SFA A				
ROM	P80C51SFBB	–40 to +85, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C51SFBB				
ROM	P80C51UBAA	0 to +70, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UBAA				
ROM	P80C51UBPN	0 to +70, Plastic Dual In-line Package	5 V	0 to 33	SOT129-1
OTP	P87C51UBPN				
ROM	P80C51UFA A	–40 to +85, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UFA A				

PART NUMBER DERIVATION

DEVICE NUMBER	DEVICE NUMBER	OPERATING FREQUENCY, MAX (S)	TEMPERATURE RANGE (B)	PACKAGE (AA)
ROM	P80C51	S = 16 MHz	B = 0° to +70°C	AA = PLCC
ROM	P80C52	S = 16 MHz	B = 0° to +70°C	AA = PLCC
OTP	P87C51	U = 33 MHz	F = –40°C to +85°C	BB = PQFP
OTP	P87C52	U = 33 MHz	F = –40°C to +85°C	BB = PQFP

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80C52/87C52 ORDERING INFORMATION

	MEMORY SIZE 8K × 8	TEMPERATURE RANGE °C AND PACKAGE	VOLTAGE RANGE	FREQ. (MHz)	DWG. #
ROM	P80C52SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C52SBPN				
ROM	P80C52SBAA	0 to +70, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C52SBAA				
ROM	P80C52SBBB	0 to +70, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C52SBBB				
ROM	P80C52SFPN	–40 to +85, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C52SFPN				
ROM	P80C52SFA A	–40 to +85, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C52SFA A				
ROM	P80C52SFBB	–40 to +85, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C52SFBB				
ROM	P80C52UBAA	0 to +70, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C52UBAA				
ROM	P80C52UBPN	0 to +70, Plastic Dual In-line Package	5 V	0 to 33	SOT129-1
OTP	P87C52UBPN				
ROM	P80C52UFA A	–40 to +85, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C52UFA A				

4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
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BLOCK DIAGRAM



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PIN DESCRIPTIONS

MNEMONIC	PIN NUMBER			TYPE	NAME AND FUNCTION
	DIP	LCC	QFP		
V _{SS}	20	22	16	I	Ground: 0 V reference.
V _{CC}	40	44	38	I	Power Supply: This is the power supply voltage for normal, idle, and power-down operation.
P0.0–P0.7	39–32	43–36	37–30	I/O	Port 0: Port 0 is an open-drain, bidirectional I/O port with Schmitt trigger inputs. Port 0 pins that have 1s written to them float and can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external program and data memory. In this application, it uses strong internal pull-ups when emitting 1s. Port 0 also outputs the code bytes during program verification and received code bytes during EPROM programming. External pull-ups are required during program verification.
P1.0–P1.7	1–8	2–9	40–44, 1–3	I/O	Port 1: Port 1 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 1 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 1 pins that are externally pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 1 also receives the low-order address byte during program memory verification. Alternate functions for Port 1 include: T2 (P1.0): Timer/Counter 2 external count input/clockout (see Programmable Clock-Out) T2EX (P1.1): Timer/Counter 2 Reload/Capture/Direction control
P2.0–P2.7	21–28	24–31	18–25	I/O	Port 2: Port 2 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 2 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 2 pins that are externally being pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @DPTR). In this application, it uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOV @Ri), port 2 emits the contents of the P2 special function register. Some Port 2 pins receive the high order address bits during EPROM programming and verification.
P3.0–P3.7	10–17	11, 13–19	5, 7–13	I/O	Port 3: Port 3 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 3 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 3 pins that are externally being pulled low will source current because of the pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 3 also serves the special features of the 80C51 family, as listed below: RxD (P3.0): Serial input port TxD (P3.1): Serial output port INT0 (P3.2): External interrupt INT1 (P3.3): External interrupt T0 (P3.4): Timer 0 external input T1 (P3.5): Timer 1 external input WR (P3.6): External data memory write strobe RD (P3.7): External data memory read strobe
RST	9	10	4	I	Reset: A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V _{SS} permits a power-on reset using only an external capacitor to V _{CC} .
ALE/PROG	30	33	27	O	Address Latch Enable/Program Pulse: Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency, and can be used for external timing or clocking. Note that one ALE pulse is skipped during each access to external data memory. This pin is also the program pulse input (PROG) during EPROM programming. ALE can be disabled by setting SFR auxiliary.0. With this bit set, ALE will be active only during a MOVX instruction.
PSEN	29	32	26	O	Program Store Enable: The read strobe to external program memory. When the device is executing code from the external program memory, PSEN is activated twice each machine cycle, except that two PSEN activations are skipped during each access to external data memory. PSEN is not activated during fetches from internal program memory.
EA/V _{PP}	31	35	29	I	External Access Enable/Programming Supply Voltage: EA must be externally held low to enable the device to fetch code from external program memory locations 0000H to 0FFFFH. If EA is held high, the device executes from internal program memory unless the program counter contains an address greater than the on-chip ROM/OTP. This pin also receives the 12.75 V programming supply voltage (V _{PP}) during EPROM programming. If security bit 1 is programmed, EA will be internally latched on Reset.
XTAL1	19	21	15	I	Crystal 1: Input to the inverting oscillator amplifier and input to the internal clock generator circuits.
XTAL2	18	20	14	O	Crystal 2: Output from the inverting oscillator amplifier.

NOTE:

To avoid "latch-up" effect at power-on, the voltage on any pin at any time must not be higher than V_{CC} + 0.5 V or V_{SS} – 0.5 V, respectively.

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Table 1. 80C51/87C51/80C52/87C52 Special Function Registers

SYMBOL	DESCRIPTION	DIRECT ADDRESS	BIT ADDRESS, SYMBOL, OR ALTERNATIVE PORT FUNCTION								RESET VALUE
			MSB							LSB	
ACC*	Accumulator	E0H	E7	E6	E5	E4	E3	E2	E1	E0	00H
AUXR#	Auxiliary	8EH	–	–	–	–	–	–	–	AO	xxxxxxx0B
AUXR1#	Auxiliary 1	A2H	–	–	–	LPEP ²	WUPD	0	–	DPS	xxx000x0B
B*	B register	F0H	F7	F6	F5	F4	F3	F2	F1	F0	00H
DPTR:	Data Pointer (2 bytes)										
DPH	Data Pointer High	83H									00H
DPL	Data Pointer Low	82H									00H
			AF	AE	AD	AC	AB	AA	A9	A8	
IE*	Interrupt Enable	A8H	EA	–	ET2	ES	ET1	EX1	ET0	EX0	0x000000B
			BF	BE	BD	BC	BB	BA	B9	B8	
IP*	Interrupt Priority	B8H	–	–	PT2	PS	PT1	PX1	PT0	PX0	xx000000B
			B7	B6	B5	B4	B3	B2	B1	B0	
IPH#	Interrupt Priority High	B7H	–	–	PT2H	PSH	PT1H	PX1H	PT0H	PX0H	xx000000B
			87	86	85	84	83	82	81	80	
P0*	Port 0	80H	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	FFH
			97	96	95	94	93	92	91	90	
P1*	Port 1	90H	–	–	–	–	–	–	T2EX	T2	FFH
			A7	A6	A5	A4	A3	A2	A1	A0	
P2*	Port 2	A0H	AD15	AD14	AD13	AD12	AD11	AD10	AD9	AD8	FFH
			B7	B6	B5	B4	B3	B2	B1	B0	
P3*	Port 3	B0H	RD	WR	T1	T0	INT1	INT0	TxD	RxD	FFH
PCON# ¹	Power Control	87H	SMOD1	SMOD0	–	POF	GF1	GF0	PD	IDL	00xx0000B
			D7	D6	D5	D4	D3	D2	D1	D0	
			CY	AC	F0	RS1	RS0	OV	–	P	000000x0B
PSW*	Program Status Word	D0H									00H
RACAP2H#	Timer 2 Capture High	CBH									00H
RACAP2L#	Timer 2 Capture Low	CAH									00H
SADDR#	Slave Address	A9H									00H
SADEN#	Slave Address Mask	B9H									00H
SBUF	Serial Data Buffer	99H									xxxxxxxxxB
			9F	9E	9D	9C	9B	9A	99	98	
SCON*	Serial Control	98H	SM0/FE	SM1	SM2	REN	TB8	RB8	T1	R1	00H
SP	Stack Pointer	81H									07H
			8F	8E	8D	8C	8B	8A	89	88	
TCON*	Timer Control	88H	TF1	TR1	TF0	TR0	IE1	IT1	IE0	IT0	00H
			CF	CE	CD	CC	CB	CA	C9	C8	
T2CON*	Timer 2 Control	C8H	TF2	EXF2	RCLK	TCLK	EXEN2	TR2	C/T2	CP/RL2	00H
T2MOD#	Timer 2 Mode Control	C9H	–	–	–	–	–	–	T2OE	DCEN	xxxxxx00B
TH0	Timer High 0	8CH									00H
TH1	Timer High 1	8DH									00H
TH2#	Timer High 2	CDH									00H
TL0	Timer Low 0	8AH									00H
TL1	Timer Low 1	8BH									00H
TL2#	Timer Low 2	CCH									00H
TMOD	Timer Mode	89H	GATE	C/T	M1	M0	GATE	C/T	M1	M0	00H

NOTE:

Unused register bits that are not defined should not be set by the user's program. If violated, the device could function incorrectly.

* SFRs are bit addressable.

SFRs are modified from or added to the 80C51 SFRs.

– Reserved bits.

1. Reset value depends on reset source.

2. LPEP – Low Power EPROM operation (OTP/EPROM only)

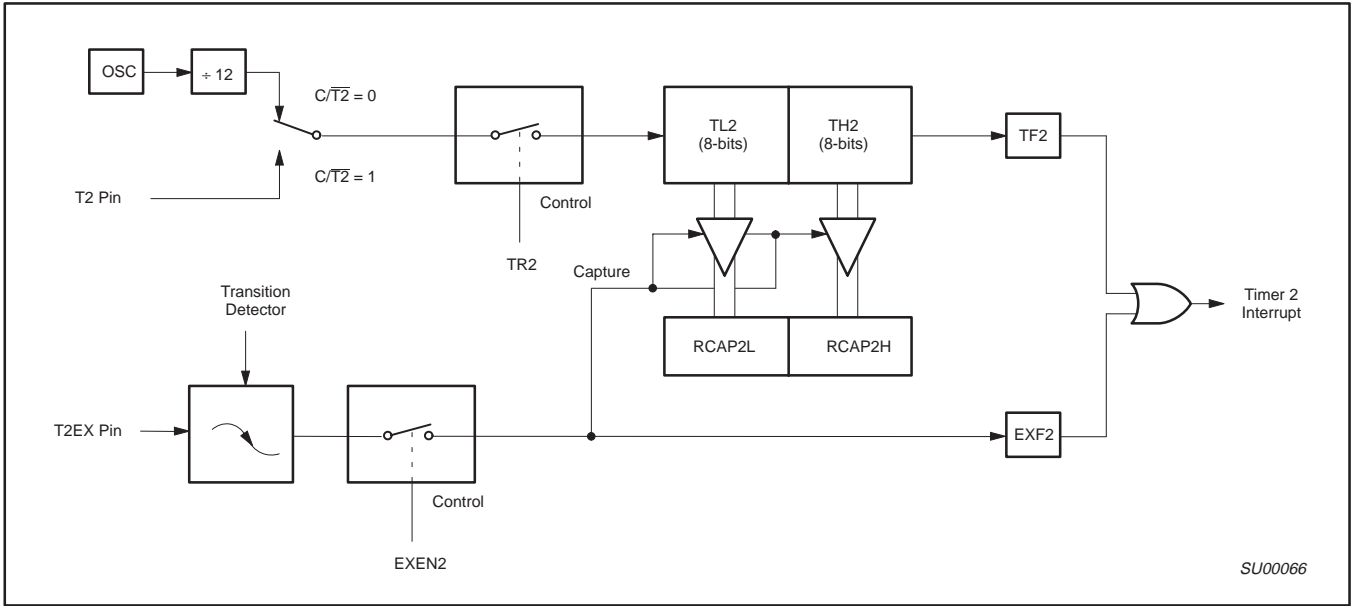
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(MSB)				(LSB)			
TF2	EXF2	RCLK	TCLK	EXEN2	TR2	C/T2	CP/RL2
Symbol	Position	Name and Significance					
TF2	T2CON.7	Timer 2 overflow flag set by a Timer 2 overflow and must be cleared by software. TF2 will not be set when either RCLK or TCLK = 1.					
EXF2	T2CON.6	Timer 2 external flag set when either a capture or reload is caused by a negative transition on T2EX and EXEN2 = 1. When Timer 2 interrupt is enabled, EXF2 = 1 will cause the CPU to vector to the Timer 2 interrupt routine. EXF2 must be cleared by software. EXF2 does not cause an interrupt in up/down counter mode (DCEN = 1).					
RCLK	T2CON.5	Receive clock flag. When set, causes the serial port to use Timer 2 overflow pulses for its receive clock in modes 1 and 3. RCLK = 0 causes Timer 1 overflow to be used for the receive clock.					
TCLK	T2CON.4	Transmit clock flag. When set, causes the serial port to use Timer 2 overflow pulses for its transmit clock in modes 1 and 3. TCLK = 0 causes Timer 1 overflows to be used for the transmit clock.					
EXEN2	T2CON.3	Timer 2 external enable flag. When set, allows a capture or reload to occur as a result of a negative transition on T2EX if Timer 2 is not being used to clock the serial port. EXEN2 = 0 causes Timer 2 to ignore events at T2EX.					
TR2	T2CON.2	Start/stop control for Timer 2. A logic 1 starts the timer.					
C/T2	T2CON.1	Timer or counter select. (Timer 2) 0 = Internal timer (OSC/12) 1 = External event counter (falling edge triggered).					
CP/RL2	T2CON.0	Capture/Reload flag. When set, captures will occur on negative transitions at T2EX if EXEN2 = 1. When cleared, auto-reloads will occur either with Timer 2 overflows or negative transitions at T2EX when EXEN2 = 1. When either RCLK = 1 or TCLK = 1, this bit is ignored and the timer is forced to auto-reload on Timer 2 overflow.					

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Figure 1. Timer/Counter 2 (T2CON) Control Register

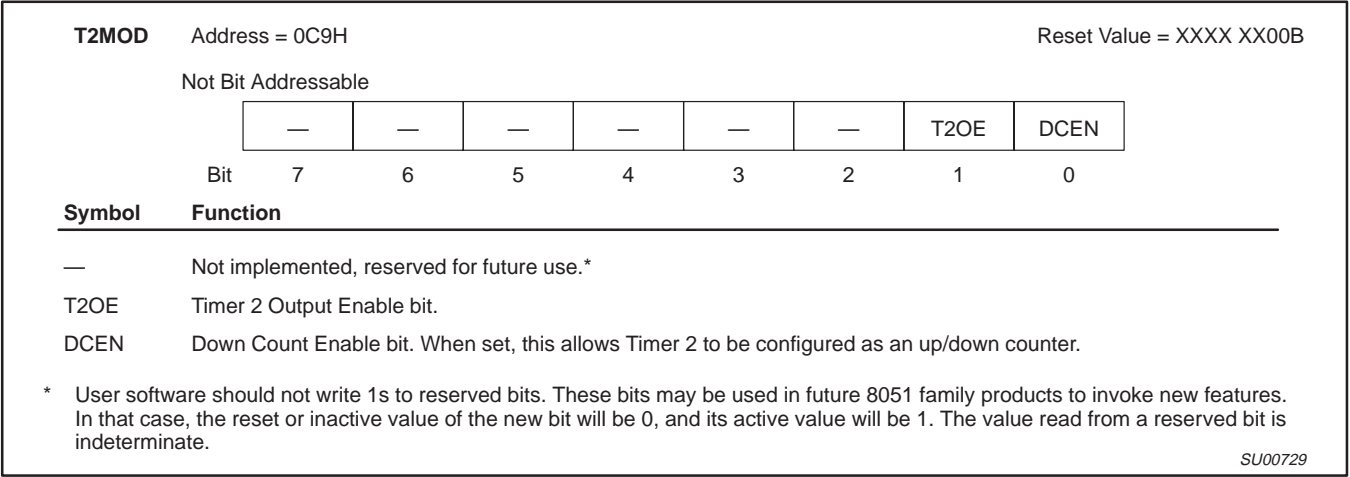


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Figure 2. Timer 2 in Capture Mode

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Baud Rate Generator Mode

Bits TCLK and/or RCLK in T2CON (Table 3) allow the serial port transmit and receive baud rates to be derived from either Timer 1 or Timer 2. When TCLK= 0, Timer 1 is used as the serial port transmit baud rate generator. When TCLK= 1, Timer 2 is used as the serial port transmit baud rate generator. RCLK has the same effect for the serial port receive baud rate. With these two bits, the serial port can have different receive and transmit baud rates – one generated by Timer 1, the other by Timer 2.

Figure 6 shows the Timer 2 in baud rate generation mode. The baud rate generation mode is like the auto-reload mode, in that a rollover in TH2 causes the Timer 2 registers to be reloaded with the 16-bit value in registers RCAP2H and RCAP2L, which are preset by software.

The baud rates in modes 1 and 3 are determined by Timer 2's overflow rate given below:

$$\text{Modes 1 and 3 Baud Rates} = \frac{\text{Timer 2 Overflow Rate}}{16}$$

The timer can be configured for either "timer" or "counter" operation. In many applications, it is configured for "timer" operation (C/T2*=0). Timer operation is different for Timer 2 when it is being used as a baud rate generator.

Usually, as a timer it would increment every machine cycle (i.e., 1/12 the oscillator frequency). As a baud rate generator, it increments every state time (i.e., 1/2 the oscillator frequency). Thus the baud rate formula is as follows:

$$\text{Modes 1 and 3 Baud Rates} = \frac{\text{Oscillator Frequency}}{[32 \times [65536 - (\text{RCAP2H}, \text{RCAP2L})]]}$$

Where: (RCAP2H, RCAP2L)= The content of RCAP2H and RCAP2L taken as a 16-bit unsigned integer.

The Timer 2 as a baud rate generator mode shown in Figure 6, is valid only if RCLK and/or TCLK = 1 in T2CON register. Note that a rollover in TH2 does not set TF2, and will not generate an interrupt. Thus, the Timer 2 interrupt does not have to be disabled when Timer 2 is in the baud rate generator mode. Also if the EXEN2 (T2 external enable flag) is set, a 1-to-0 transition in T2EX (Timer/counter 2 trigger input) will set EXF2 (T2 external flag) but will not cause a reload from (RCAP2H, RCAP2L) to (TH2, TL2). Therefore when Timer 2 is in use as a baud rate generator, T2EX can be used as an additional external interrupt, if needed.

When Timer 2 is in the baud rate generator mode, one should not try to read or write TH2 and TL2. As a baud rate generator, Timer 2 is incremented every state time (osc/2) or asynchronously from pin T2;

under these conditions, a read or write of TH2 or TL2 may not be accurate. The RCAP2 registers may be read, but should not be written to, because a write might overlap a reload and cause write and/or reload errors. The timer should be turned off (clear TR2) before accessing the Timer 2 or RCAP2 registers.

Table 4 shows commonly used baud rates and how they can be obtained from Timer 2.

Table 4. Timer 2 Generated Commonly Used Baud Rates

Baud Rate	Osc Freq	Timer 2	
		RCAP2H	RCAP2L
375 K	12 MHz	FF	FF
9.6 K	12 MHz	FF	D9
2.8 K	12 MHz	FF	B2
2.4 K	12 MHz	FF	64
1.2 K	12 MHz	FE	C8
300	12 MHz	FB	1E
110	12 MHz	F2	AF
300	6 MHz	FD	8F
110	6 MHz	F9	57

Summary Of Baud Rate Equations

Timer 2 is in baud rate generating mode. If Timer 2 is being clocked through pin T2(P1.0) the baud rate is:

$$\text{Baud Rate} = \frac{\text{Timer 2 Overflow Rate}}{16}$$

If Timer 2 is being clocked internally, the baud rate is:

$$\text{Baud Rate} = \frac{f_{\text{osc}}}{[32 \times [65536 - (\text{RCAP2H}, \text{RCAP2L})]]}$$

Where f_{osc} = Oscillator Frequency

To obtain the reload value for RCAP2H and RCAP2L, the above equation can be rewritten as:

$$\text{RCAP2H, RCAP2L} = 65536 - \left(\frac{f_{\text{osc}}}{32 \times \text{Baud Rate}} \right)$$

Timer/Counter 2 Set-up

Except for the baud rate generator mode, the values given for T2CON do not include the setting of the TR2 bit. Therefore, bit TR2 must be set, separately, to turn the timer on. See Table 5 for set-up of Timer 2 as a timer. Also see Table 6 for set-up of Timer 2 as a counter.

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Interrupt Priority Structure

The 80C51/87C51 and 80C52/87C52 have a 6-source four-level interrupt structure. They are the IE, IP and IPH. (See Figures 10, 11, and 12.) The IPH (Interrupt Priority High) register that makes the four-level interrupt structure possible. The IPH is located at SFR address B7H. The structure of the IPH register and a description of its bits is shown in Figure 12.

The function of the IPH SFR is simple and when combined with the IP SFR determines the priority of each interrupt. The priority of each interrupt is determined as shown in the following table:

PRIORITY BITS		INTERRUPT PRIORITY LEVEL
IPH.x	IP.x	
0	0	Level 0 (lowest priority)
0	1	Level 1
1	0	Level 2
1	1	Level 3 (highest priority)

An interrupt will be serviced as long as an interrupt of equal or higher priority is not already being serviced. If an interrupt of equal or higher level priority is being serviced, the new interrupt will wait until it is finished before being serviced. If a lower priority level interrupt is being serviced, it will be stopped and the new interrupt serviced. When the new interrupt is finished, the lower priority level interrupt that was stopped will be completed.

Table 7. Interrupt Table

SOURCE	POLLING PRIORITY	REQUEST BITS	HARDWARE CLEAR?	VECTOR ADDRESS
X0	1	IE0	N (L) ¹ Y (T) ²	03H
T0	2	TP0	Y	0BH
X1	3	IE1	N (L) Y (T)	13H
T1	4	TF1	Y	1BH
SP	5	RI, TI	N	23H
T2	6	TF2, EXF2	N	2BH

NOTES:

1. L = Level activated
2. T = Transition activated

		7	6	5	4	3	2	1	0
IE (0A8H)		EA	—	ET2	ES	ET1	EX1	ET0	EX0
		Enable Bit = 1 enables the interrupt. Enable Bit = 0 disables it.							
BIT	SYMBOL	FUNCTION							
IE.7	EA	Global disable bit. If EA = 0, all interrupts are disabled. If EA = 1, each interrupt can be individually enabled or disabled by setting or clearing its enable bit.							
IE.6	—	Not implemented. Reserved for future use.							
IE.5	ET2	Timer 2 interrupt enable bit.							
IE.4	ES	Serial Port interrupt enable bit.							
IE.3	ET1	Timer 1 interrupt enable bit.							
IE.2	EX1	External interrupt 1 enable bit.							
IE.1	ET0	Timer 0 interrupt enable bit.							
IE.0	EX0	External interrupt 0 enable bit.							

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Figure 10. IE Registers

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Reduced EMI

All port pins of the 8xC51 and 8xC52 have slew rate controlled outputs. This is to limit noise generated by quickly switching output signals. The slew rate is factory set to approximately 10 ns rise and fall times.

Reduced EMI Mode

The AO bit (AUXR.0) in the AUXR register when set disables the ALE output.

AUXR (8EH)

7	6	5	4	3	2	1	0
–	–	–	–	–	–	–	AO
AUXR.0		AO		Turns off ALE output.			

Dual DPTR

The dual DPTR structure (see Figure 13) enables a way to specify the address of an external data memory location. There are two 16-bit DPTR registers that address the external memory, and a single bit called DPS = AUXR1/bit0 that allows the program code to switch between them.

- New Register Name: AUXR1#
- SFR Address: A2H
- Reset Value: xxx000x0B

AUXR1 (A2H)

7	6	5	4	3	2	1	0
–	–	–	LPEP	WUPD	0	–	DPS

Where:

DPS = AUXR1/bit0 = Switches between DPTR0 and DPTR1.

Select Reg	DPS
DPTR0	0
DPTR1	1

The DPS bit status should be saved by software when switching between DPTR0 and DPTR1.

Note that bit 2 is not writable and is always read as a zero. This allows the DPS bit to be quickly toggled simply by executing an INC DPTR instruction without affecting the WOPD or LPEP bits.

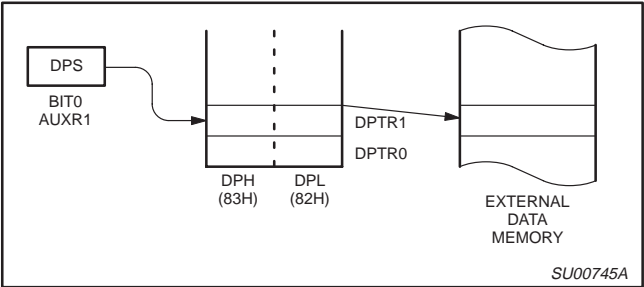


Figure 13.

DPTR Instructions

The instructions that refer to DPTR refer to the data pointer that is currently selected using the AUXR1/bit 0 register. The six instructions that use the DPTR are as follows:

INC DPTR	Increments the data pointer by 1
MOV DPTR, #data16	Loads the DPTR with a 16-bit constant
MOV A, @ A+DPTR	Move code byte relative to DPTR to ACC
MOVX A, @ DPTR	Move external RAM (16-bit address) to ACC
MOVX @ DPTR, A	Move ACC to external RAM (16-bit address)
JMP @ A + DPTR	Jump indirect relative to DPTR

The data pointer can be accessed on a byte-by-byte basis by specifying the low or high byte in an instruction which accesses the SFRs. See application note AN458 for more details.

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

ABSOLUTE MAXIMUM RATINGS^{1, 2, 3}

PARAMETER	RATING	UNIT
Operating temperature under bias	0 to +70 or –40 to +85	°C
Storage temperature range	–65 to +150	°C
Voltage on \overline{EA}/V_{PP} pin to V_{SS}	0 to +13.0	V
Voltage on any other pin to V_{SS}	–0.5 to +6.5	V
Maximum I_{OL} per I/O pin	15	mA
Power dissipation (based on package heat transfer limitations, not device power consumption)	1.5	W

NOTES:

1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any conditions other than those described in the AC and DC Electrical Characteristics section of this specification is not implied.
2. This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.
3. Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V_{SS} unless otherwise noted.

AC ELECTRICAL CHARACTERISTICS

$T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ or -40°C to $+85^{\circ}\text{C}$

SYMBOL	FIGURE	PARAMETER	CLOCK FREQUENCY RANGE –f		UNIT
			MIN	MAX	
$1/t_{CLCL}$	29	Oscillator frequency Speed versions : S (16 MHz) U (33 MHz)	0 0	16 33	MHz MHz

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

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DC ELECTRICAL CHARACTERISTICS

$T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ or -40°C to $+85^{\circ}\text{C}$, 33 MHz devices; $5\text{ V} \pm 10\%$; $V_{SS} = 0\text{ V}$

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP ¹	MAX	
V_{IL}	Input low voltage ¹¹	$4.5\text{ V} < V_{CC} < 5.5\text{ V}$	-0.5		$0.2 V_{CC} - 0.1$	V
V_{IH}	Input high voltage (ports 0, 1, 2, 3, E \bar{A})		$0.2 V_{CC} + 0.9$		$V_{CC} + 0.5$	V
V_{IH1}	Input high voltage, XTAL1, RST ¹¹		$0.7 V_{CC}$		$V_{CC} + 0.5$	V
V_{OL}	Output low voltage, ports 1, 2, 3 ⁸	$V_{CC} = 4.5\text{ V}$ $I_{OL} = 1.6\text{ mA}^2$			0.4	V
V_{OL1}	Output low voltage, port 0, ALE, PSEN ^{7, 8}	$V_{CC} = 4.5\text{ V}$ $I_{OL} = 3.2\text{ mA}^2$			0.4	V
V_{OH}	Output high voltage, ports 1, 2, 3 ³	$V_{CC} = 4.5\text{ V}$ $I_{OH} = -30\mu\text{A}$	$V_{CC} - 0.7$			V
V_{OH1}	Output high voltage (port 0 in external bus mode), ALE ⁹ , PSEN ³	$V_{CC} = 4.5\text{ V}$ $I_{OH} = -3.2\text{ mA}$	$V_{CC} - 0.7$			V
I_{IL}	Logical 0 input current, ports 1, 2, 3	$V_{IN} = 0.4\text{ V}$	-1		-50	μA
I_{TL}	Logical 1-to-0 transition current, ports 1, 2, 3 ⁶	$V_{IN} = 2.0\text{ V}$ See note 4			-650	μA
I_{LI}	Input leakage current, port 0	$0.45 < V_{IN} < V_{CC} - 0.3$			± 10	μA
I_{CC}	Power supply current (see Figure 21): Active mode (see Note 5) Idle mode (see Note 5) Power-down mode or clock stopped (see Figure 25 for conditions)	See note 5 $T_{amb} = 0^{\circ}\text{C}$ to 70°C $T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		3	50 75	μA μA
R_{RST}	Internal reset pull-down resistor		40		225	$\text{k}\Omega$
C_{IO}	Pin capacitance ¹⁰ (except E \bar{A})				15	pF

NOTES:

- Typical ratings are not guaranteed. The values listed are at room temperature, 5 V.
- Capacitive loading on ports 0 and 2 may cause spurious noise to be superimposed on the V_{OL} s of ALE and ports 1 and 3. The noise is due to external bus capacitance discharging into the port 0 and port 2 pins when these pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading $> 100\text{ pF}$), the noise pulse on the ALE pin may exceed 0.8 V. In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input. I_{OL} can exceed these conditions provided that no single output sinks more than 5mA and no more than two outputs exceed the test conditions.
- Capacitive loading on ports 0 and 2 may cause the V_{OH} on ALE and PSEN to momentarily fall below the $V_{CC} - 0.7$ specification when the address bits are stabilizing.
- Pins of ports 1, 2 and 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when V_{IN} is approximately 2 V.
- See Figures 22 through 25 for I_{CC} test conditions.
Active mode: $I_{CC(\text{MAX})} = 0.9 \times \text{FREQ.} + 1.1\text{ mA}$
Idle mode: $I_{CC(\text{MAX})} = 0.18 \times \text{FREQ.} + 1.0\text{ mA}$; See Figure 21.
- This value applies to $T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$. For $T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $I_{TL} = -750\text{ }\mu\text{A}$.
- Load capacitance for port 0, ALE, and PSEN = 100 pF, load capacitance for all other outputs = 80 pF.
- Under steady state (non-transient) conditions, I_{OL} must be externally limited as follows:
Maximum I_{OL} per port pin: 15 mA (*NOTE: This is 85°C specification.)
Maximum I_{OL} per 8-bit port: 26 mA
Maximum total I_{OL} for all outputs: 71 mA
If I_{OL} exceeds the test condition, V_{OL} may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.
- ALE is tested to V_{OH1} , except when ALE is off then V_{OH} is the voltage specification.
- Pin capacitance is characterized but not tested. Pin capacitance is less than 25 pF. Pin capacitance of ceramic package is less than 15 pF (except E \bar{A} is 25 pF).
- To improve noise rejection a nominal 100 ns glitch rejection circuitry has been added to the RST pin, and a nominal 15 ns glitch rejection circuitry has been added to the INT0 and INT1 pins. Previous devices provided only an inherent 5 ns of glitch rejection.

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AC ELECTRICAL CHARACTERISTICS

$T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ or -40°C to $+85^{\circ}\text{C}$, $V_{CC} = 5\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}^{1, 2, 3}$

SYMBOL	FIGURE	PARAMETER	VARIABLE CLOCK ⁴ 16 MHz to f_{max}		33 MHz ζ CLOCK		UNIT
			MIN	MAX	MIN	MAX	
t_{HLL}	14	ALE pulse width	$2t_{CLCL}-40$		21		ns
t_{AVLL}	14	Address valid to ALE low	$t_{CLCL}-25$		5		ns
t_{LLAX}	14	Address hold after ALE low	$t_{CLCL}-25$				ns
t_{LLIV}	14	ALE low to valid instruction in		$4t_{CLCL}-65$		55	ns
t_{LLPL}	14	ALE low to $\overline{\text{PSEN}}$ low	$t_{CLCL}-25$		5		ns
t_{PLPH}	14	$\overline{\text{PSEN}}$ pulse width	$3t_{CLCL}-45$		45		ns
t_{PLIV}	14	$\overline{\text{PSEN}}$ low to valid instruction in		$3t_{CLCL}-60$		30	ns
t_{PXIX}	14	Input instruction hold after $\overline{\text{PSEN}}$	0		0		ns
t_{PXIZ}	14	Input instruction float after $\overline{\text{PSEN}}$		$t_{CLCL}-25$		5	ns
t_{AVIV}	14	Address to valid instruction in		$5t_{CLCL}-80$		70	ns
t_{PLAZ}	14	$\overline{\text{PSEN}}$ low to address float		10		10	ns
Data Memory							
t_{RLRH}	15, 16	RD pulse width	$6t_{CLCL}-100$		82		ns
t_{WLWH}	15, 16	WR pulse width	$6t_{CLCL}-100$		82		ns
t_{RLDV}	15, 16	RD low to valid data in		$5t_{CLCL}-90$		60	ns
t_{RHDX}	15, 16	Data hold after $\overline{\text{RD}}$	0		0		ns
t_{RHDZ}	15, 16	Data float after $\overline{\text{RD}}$		$2t_{CLCL}-28$		32	ns
t_{LLDV}	15, 16	ALE low to valid data in		$8t_{CLCL}-150$		90	ns
t_{AVDV}	15, 16	Address to valid data in		$9t_{CLCL}-165$		105	ns
t_{LLWL}	15, 16	ALE low to $\overline{\text{RD}}$ or $\overline{\text{WR}}$ low	$3t_{CLCL}-50$	$3t_{CLCL}+50$	40	140	ns
t_{AVWL}	15, 16	Address valid to $\overline{\text{WR}}$ low or $\overline{\text{RD}}$ low	$4t_{CLCL}-75$		45		ns
t_{QVWX}	15, 16	Data valid to $\overline{\text{WR}}$ transition	$t_{CLCL}-30$		0		ns
t_{WHQX}	15, 16	Data hold after $\overline{\text{WR}}$	$t_{CLCL}-25$		5		ns
t_{QVWH}	16	Data valid to $\overline{\text{WR}}$ high	$7t_{CLCL}-130$		80		ns
t_{RLAZ}	15, 16	RD low to address float		0		0	ns
t_{WHLH}	15, 16	RD or $\overline{\text{WR}}$ high to ALE high	$t_{CLCL}-25$	$t_{CLCL}+25$	5	55	ns
External Clock							
t_{CHCX}	18	High time	$0.38t_{CLCL}$	$t_{CLCL}-t_{CLCX}$			ns
t_{CLCX}	18	Low time	$0.38t_{CLCL}$	$t_{CLCL}-t_{CHCX}$			ns
t_{CLCH}	18	Rise time		5			ns
t_{CHCL}	18	Fall time		5			ns
Shift Register							
t_{XLXL}	17	Serial port clock cycle time	$12t_{CLCL}$		360		ns
t_{QVXH}	17	Output data setup to clock rising edge	$10t_{CLCL}-133$		167		ns
t_{XHGX}	17	Output data hold after clock rising edge	$2t_{CLCL}-80$				ns
t_{XHDX}	17	Input data hold after clock rising edge	0		0		ns
t_{XHDX}	17	Clock rising edge to input data valid		$10t_{CLCL}-133$		167	ns

NOTES:

- Parameters are valid over operating temperature range unless otherwise specified.
- Load capacitance for port 0, ALE, and $\overline{\text{PSEN}}$ = 100 pF, load capacitance for all other outputs = 80 pF.
- Interfacing the 87C51, 80C51, 87C52 or 80C52 to devices with float times up to 45ns is permitted. This limited bus contention will not cause damage to Port 0 drivers.
- Variable clock is specified for oscillator frequencies greater than 16 MHz to 33 MHz. For frequencies equal or less than 16 MHz, see 16 MHz "AC Electrical Characteristics", page 24.
- Parts are guaranteed to operate down to 0 Hz. When an external clock source is used, the RST pin should be held high for a minimum of 20 μs for power-on or wakeup from power down.

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Table 9. Program Security Bits for EPROM Devices

PROGRAM LOCK BITS ^{1, 2}				PROTECTION DESCRIPTION
	SB1	SB2	SB3	
1	U	U	U	No Program Security features enabled. (Code verify will still be encrypted by the Encryption Array if programmed.)
2	P	U	U	MOVC instructions executed from external program memory are disabled from fetching code bytes from internal memory, \overline{EA} is sampled and latched on Reset, and further programming of the EPROM is disabled.
3	P	P	U	Same as 2, also verify is disabled.
4	P	P	P	Same as 3, external execution is disabled. Internal data RAM is not accessible.

- NOTES:
1. P – programmed. U – unprogrammed.
 2. Any other combination of the security bits is not defined.

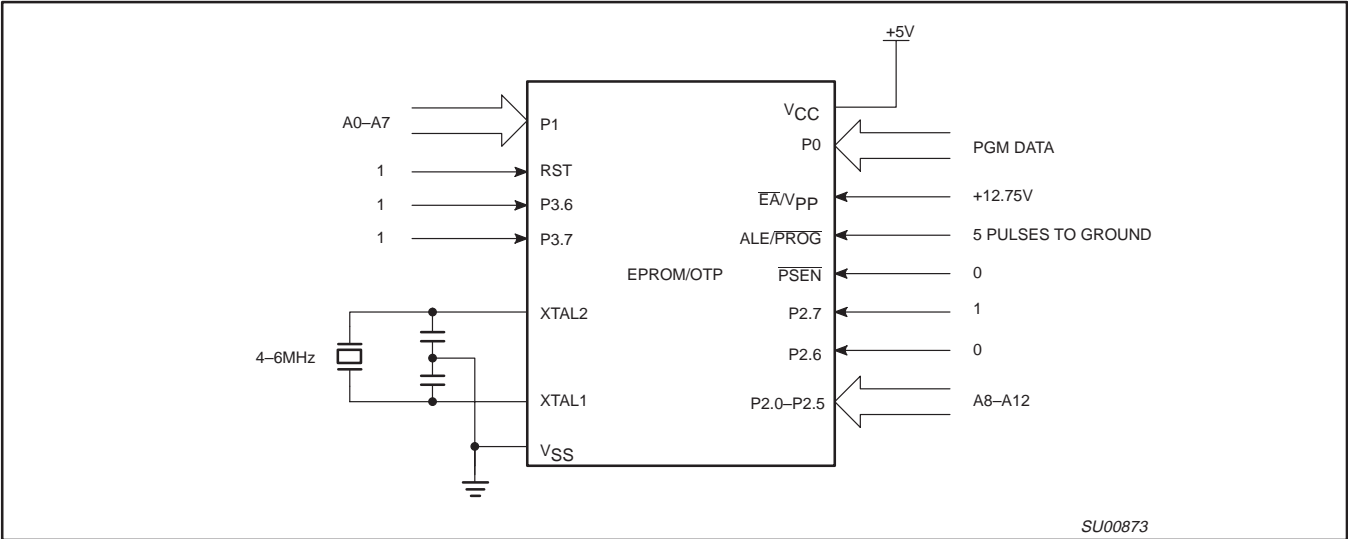


Figure 26. Programming Configuration

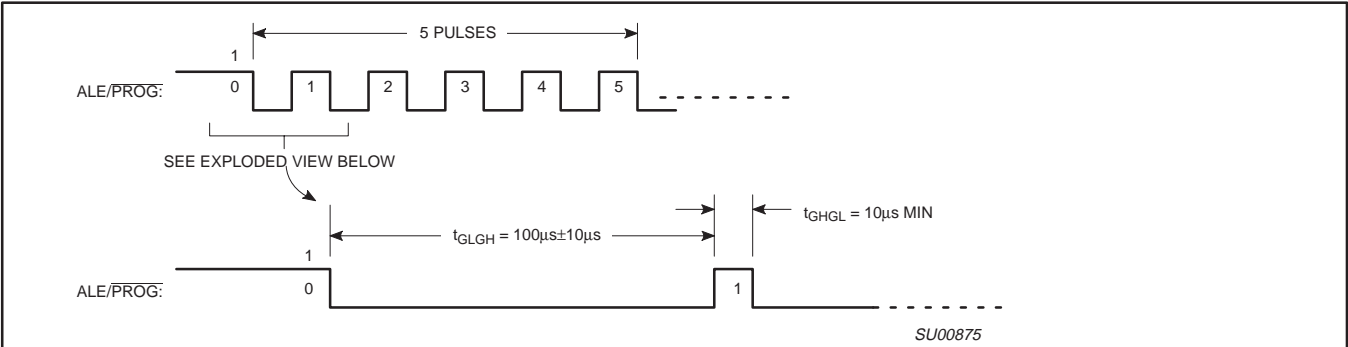


Figure 27. \overline{PROG} Waveform

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

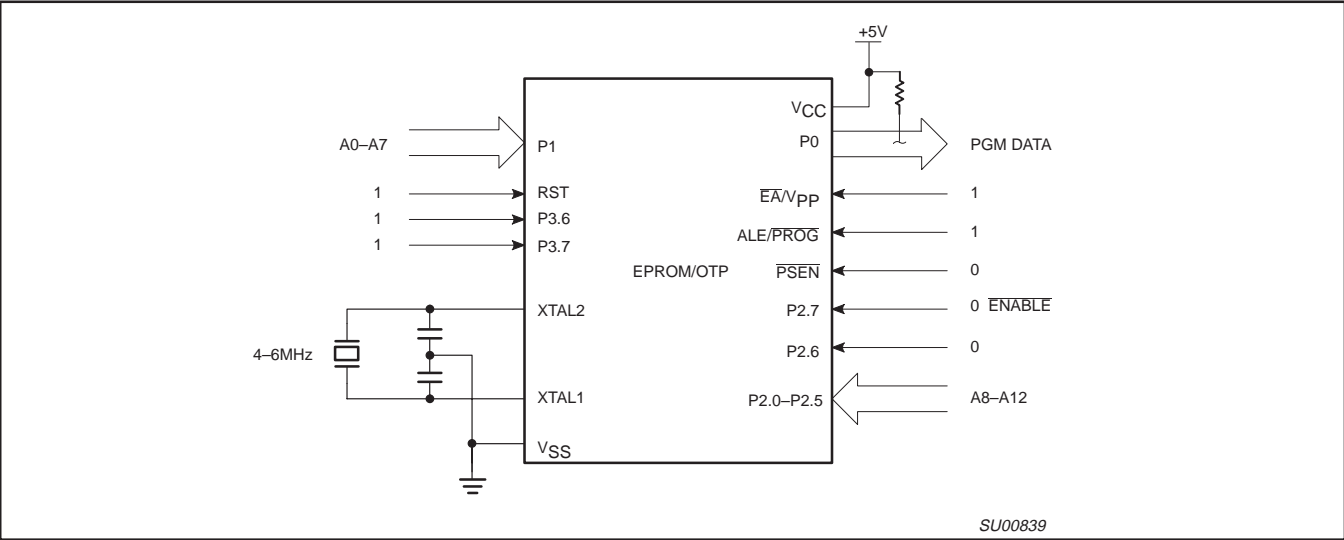


Figure 28. Program Verification

EPROM PROGRAMMING AND VERIFICATION CHARACTERISTICS

T_{amb} = 21°C to +27°C, V_{CC} = 5 V±10%, V_{SS} = 0 V (See Figure 29)

SYMBOL	PARAMETER	MIN	MAX	UNIT
V _{PP}	Programming supply voltage	12.5	13.0	V
I _{PP}	Programming supply current		50 ¹	mA
1/t _{CLCL}	Oscillator frequency	4	6	MHz
t _{AVGL}	Address setup to $\overline{\text{PROG}}$ low	48t _{CLCL}		
t _{GHAX}	Address hold after $\overline{\text{PROG}}$	48t _{CLCL}		
t _{DVGL}	Data setup to $\overline{\text{PROG}}$ low	48t _{CLCL}		
t _{GHDx}	Data hold after $\overline{\text{PROG}}$	48t _{CLCL}		
t _{EHS}	P2.7 (ENABLE) high to V _{PP}	48t _{CLCL}		
t _{SHGL}	V _{PP} setup to $\overline{\text{PROG}}$ low	10		μs
t _{GHSL}	V _{PP} hold after $\overline{\text{PROG}}$	10		μs
t _{GLGH}	$\overline{\text{PROG}}$ width	90	110	μs
t _{AVQV}	Address to data valid		48t _{CLCL}	
t _{ELQZ}	ENABLE low to data valid		48t _{CLCL}	
t _{EHQZ}	Data float after ENABLE	0	48t _{CLCL}	
t _{GHGL}	$\overline{\text{PROG}}$ high to $\overline{\text{PROG}}$ low	10		μs

NOTE:
1. Not tested.

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

80C51 ROM CODE SUBMISSION

When submitting ROM code for the 80C51, the following must be specified:

1. 4k byte user ROM data
2. 64 byte ROM encryption key
3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 0FFFFH	DATA	7:0	User ROM Data
1000H to 103FH	KEY	7:0	ROM Encryption Key
1040H	SEC	0	ROM Security Bit 1
1040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

1. External MOVC is disabled, and
2. \overline{EA} is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

- Security Bit #1: ☐ Enabled ☐ Disabled
- Security Bit #2: ☐ Enabled ☐ Disabled
- Encryption: ☐ No ☐ Yes If Yes, must send key file.

80C52 ROM CODE SUBMISSION

When submitting ROM code for the 80C52, the following must be specified:

1. 8k byte user ROM data
2. 64 byte ROM encryption key
3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 1FFFFH	DATA	7:0	User ROM Data
2000H to 203FH	KEY	7:0	ROM Encryption Key
2040H	SEC	0	ROM Security Bit 1
2040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

1. External MOVC is disabled, and
2. \overline{EA} is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

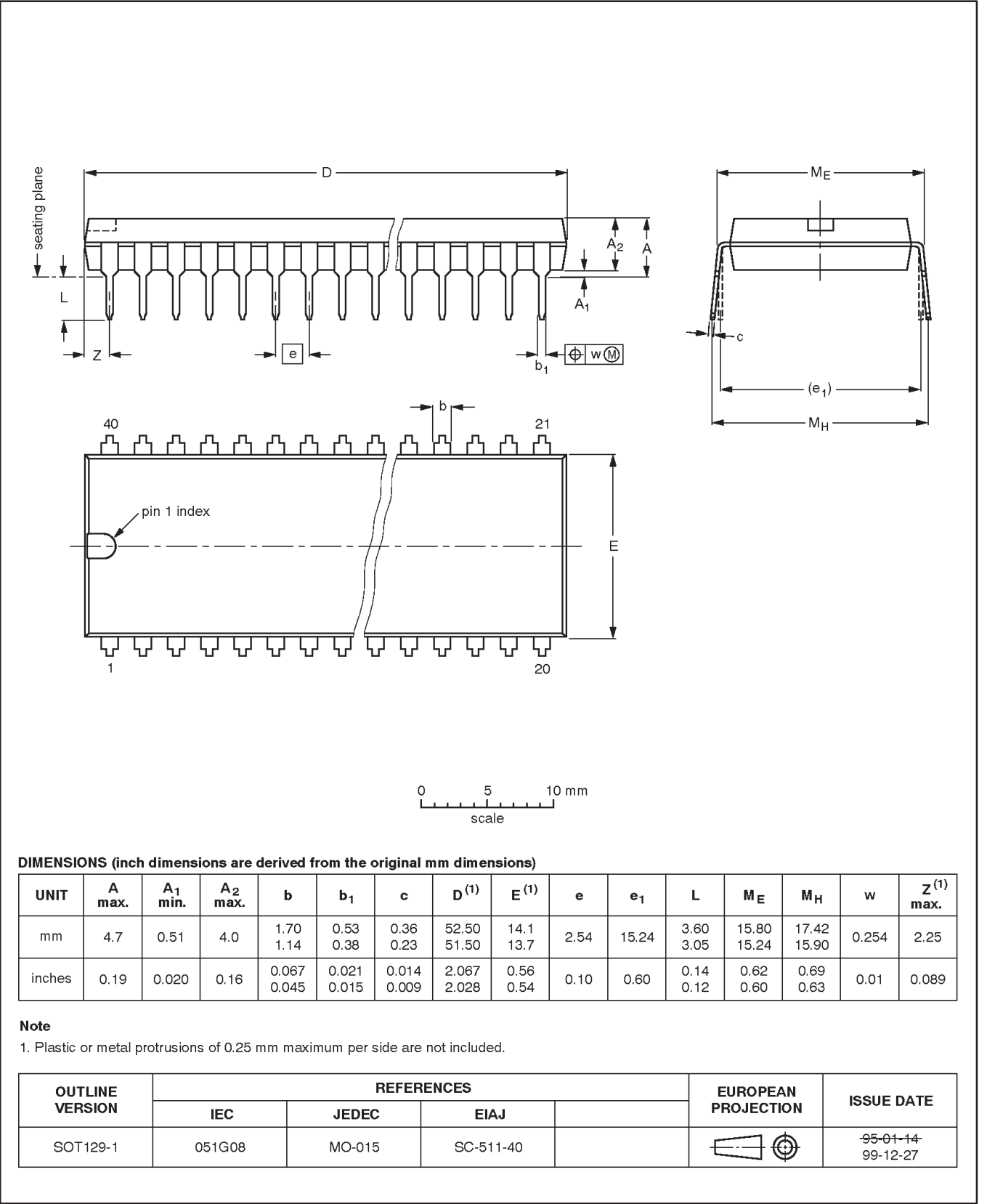
- Security Bit #1: ☐ Enabled ☐ Disabled
- Security Bit #2: ☐ Enabled ☐ Disabled
- Encryption: ☐ No ☐ Yes If Yes, must send key file.

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

DIP40: plastic dual in-line package; 40 leads (600 mil)

SOT129-1

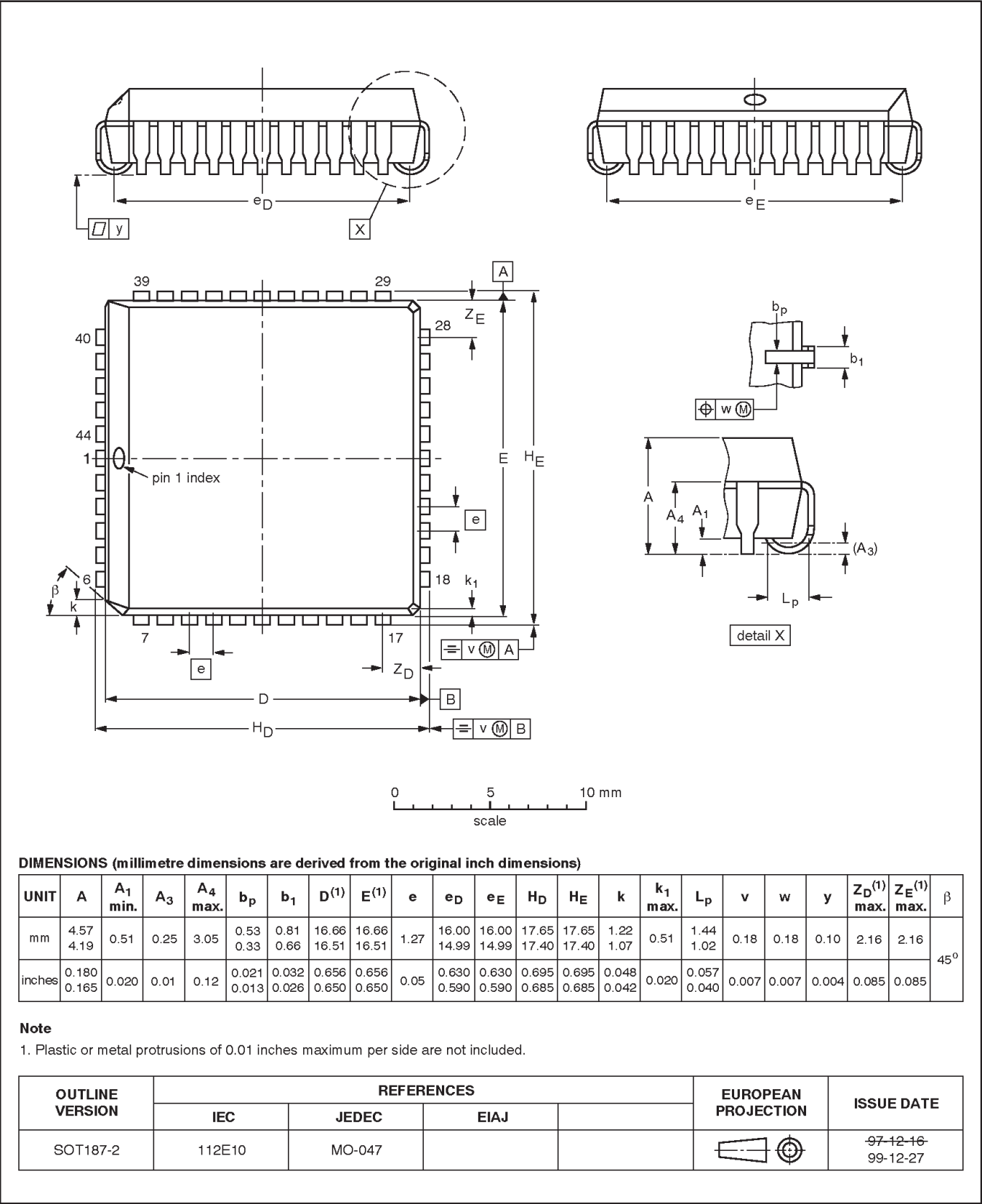


80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

PLCC44: plastic leaded chip carrier; 44 leads

SOT187-2



80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Date of release: 08-00

Document order number:

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